



Standard Rectifier

$$V_{RRM} = 2 \times 1200 \text{ V}$$

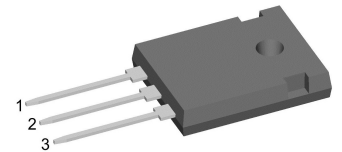
$$I_{FAV} = 30 \text{ A}$$

$$V_F = 1.2 \text{ V}$$

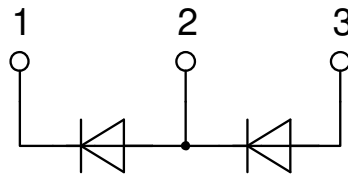
Phase leg

Part number

DMA30P1200HB



Backside: anode/cathode



Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very low forward voltage drop
- Improved thermal behaviour
- High commutation robustness
- High surge capability

Applications:

- Diode for main rectification
- For single and three phase bridge configurations

Package: TO-247

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

Disclaimer Notice

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| Rectifier | | | | Ratings | | | |
|------------|--|---|-------------------------|---------|------|------------------|--|
| Symbol | Definition | Conditions | min. | typ. | max. | Unit | |
| V_{RSM} | max. non-repetitive reverse blocking voltage | $T_{VJ} = 25^{\circ}C$ | | | 1300 | V | |
| V_{RRM} | max. repetitive reverse blocking voltage | $T_{VJ} = 25^{\circ}C$ | | | 1200 | V | |
| I_R | reverse current | $V_R = 1200\text{ V}$ | $T_{VJ} = 25^{\circ}C$ | | 40 | μA | |
| | | $V_R = 1200\text{ V}$ | $T_{VJ} = 150^{\circ}C$ | | 1.5 | mA | |
| V_F | forward voltage drop | $I_F = 30\text{ A}$ | $T_{VJ} = 25^{\circ}C$ | | 1.26 | V | |
| | | $I_F = 60\text{ A}$ | | | 1.53 | V | |
| | | $I_F = 30\text{ A}$ | $T_{VJ} = 150^{\circ}C$ | | 1.20 | V | |
| | | $I_F = 60\text{ A}$ | | | 1.57 | V | |
| I_{FAV} | average forward current | $T_C = 130^{\circ}C$ 180° sine | $T_{VJ} = 175^{\circ}C$ | | 30 | A | |
| V_{FO} | threshold voltage | } for power loss calculation only | $T_{VJ} = 175^{\circ}C$ | | 0.81 | V | |
| r_F | slope resistance | | | | 12.7 | m Ω | |
| R_{thJC} | thermal resistance junction to case | | | | 0.8 | K/W | |
| R_{thCH} | thermal resistance case to heatsink | | | 0.3 | | K/W | |
| P_{tot} | total power dissipation | | $T_C = 25^{\circ}C$ | | 185 | W | |
| I_{FSM} | max. forward surge current | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$ | $T_{VJ} = 45^{\circ}C$ | | 370 | A | |
| | | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$ | $V_R = 0\text{ V}$ | | 400 | A | |
| | | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$ | $T_{VJ} = 150^{\circ}C$ | | 315 | A | |
| | | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$ | $V_R = 0\text{ V}$ | | 340 | A | |
| I^2t | value for fusing | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$ | $T_{VJ} = 45^{\circ}C$ | | 685 | A ² s | |
| | | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$ | $V_R = 0\text{ V}$ | | 665 | A ² s | |
| | | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$ | $T_{VJ} = 150^{\circ}C$ | | 495 | A ² s | |
| | | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$ | $V_R = 0\text{ V}$ | | 480 | A ² s | |
| C_J | junction capacitance | $V_R = 400\text{ V}; f = 1\text{ MHz}$ | $T_{VJ} = 25^{\circ}C$ | | 11 | pF | |



| Package TO-247 | | | Ratings | | | |
|----------------|------------------------------|--------------|---------|------|------|------|
| Symbol | Definition | Conditions | min. | typ. | max. | Unit |
| I_{RMS} | RMS current | per terminal | | | 70 | A |
| T_{VJ} | virtual junction temperature | | -55 | | 175 | °C |
| T_{op} | operation temperature | | -55 | | 150 | °C |
| T_{stg} | storage temperature | | -55 | | 150 | °C |
| Weight | | | | 6 | | g |
| M_D | mounting torque | | 0.8 | | 1.2 | Nm |
| F_C | mounting force with clip | | 20 | | 120 | N |

Product Marking



Part description

- D = Diode
- M = Standard Rectifier
- A = (up to 1800V)
- 30 = Current Rating [A]
- P = Phase leg
- 1200 = Reverse Voltage [V]
- HB = TO-247AD (3)

| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-----------------|--------------------|---------------|----------|----------|
| Standard | DMA30P1200HB | DMA30P1200HB | Tube | 30 | 522386 |

| Similar Part | Package | Voltage class |
|--------------|--------------|---------------|
| DMA30P1600HB | TO-247AD (3) | 1600 |

Equivalent Circuits for Simulation

* on die level

$T_{VJ} = 175^{\circ}C$



Rectifier

| | | | |
|--------------|--------------------|------|----|
| $V_{0 \max}$ | threshold voltage | 0.81 | V |
| $R_{0 \max}$ | slope resistance * | 10.1 | mΩ |



Outlines TO-247



| Sym. | Inches | | Millimeter | |
|------|-------------|-------|------------|-------|
| | min. | max. | min. | max. |
| A | 0.185 | 0.209 | 4.70 | 5.30 |
| A1 | 0.087 | 0.102 | 2.21 | 2.59 |
| A2 | 0.059 | 0.098 | 1.50 | 2.49 |
| D | 0.819 | 0.845 | 20.79 | 21.45 |
| E | 0.610 | 0.640 | 15.48 | 16.24 |
| E2 | 0.170 | 0.216 | 4.31 | 5.48 |
| e | 0.215 BSC | | 5.46 BSC | |
| L | 0.780 | 0.800 | 19.80 | 20.30 |
| L1 | - | 0.177 | - | 4.49 |
| Ø P | 0.140 | 0.144 | 3.55 | 3.65 |
| Q | 0.212 0.244 | | 5.38 6.19 | |
| S | 0.242 BSC | | 6.14 BSC | |
| b | 0.039 | 0.055 | 0.99 | 1.40 |
| b2 | 0.065 | 0.094 | 1.65 | 2.39 |
| b4 | 0.102 | 0.135 | 2.59 | 3.43 |
| c | 0.015 | 0.035 | 0.38 | 0.89 |
| D1 | 0.515 | - | 13.07 | - |
| D2 | 0.020 | 0.053 | 0.51 | 1.35 |
| E1 | 0.530 | - | 13.45 | - |
| Ø P1 | - | 0.29 | - | 7.39 |



Rectifier

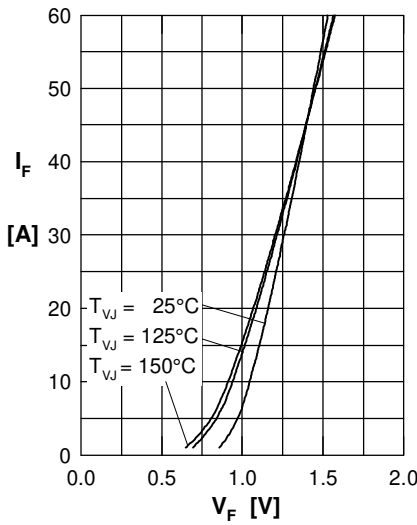


Fig. 1 Forward current versus voltage drop per diode

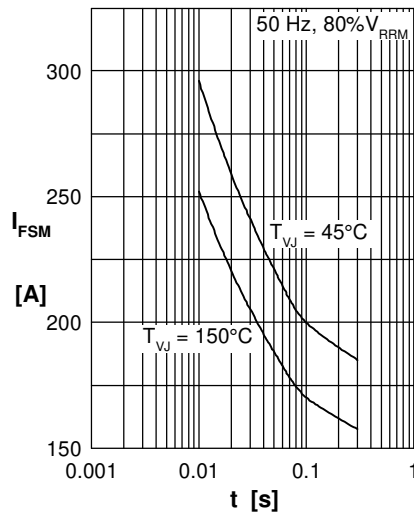


Fig. 2 Surge overload current versus time per diode

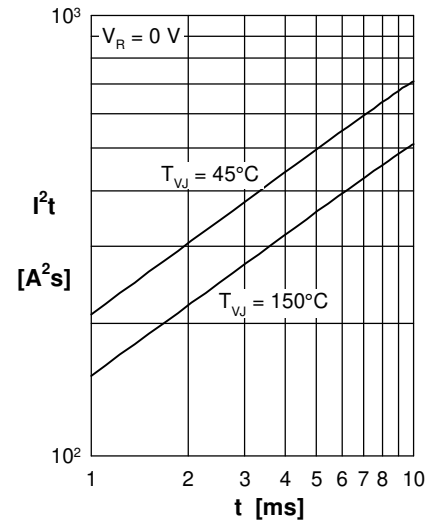


Fig. 3 I^2t versus time per diode

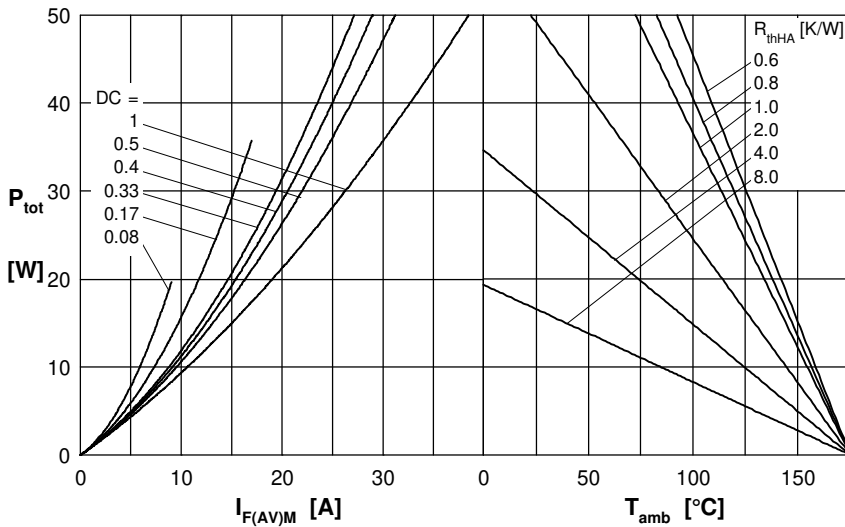


Fig. 4 Power dissipation versus direct output current and ambient temperature per diode

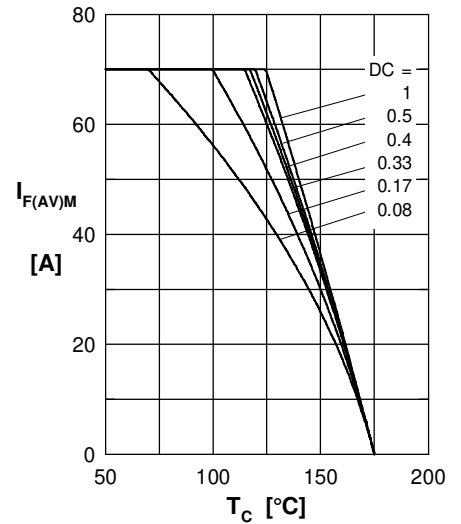


Fig. 5 Max. forward current versus case temperature per diode

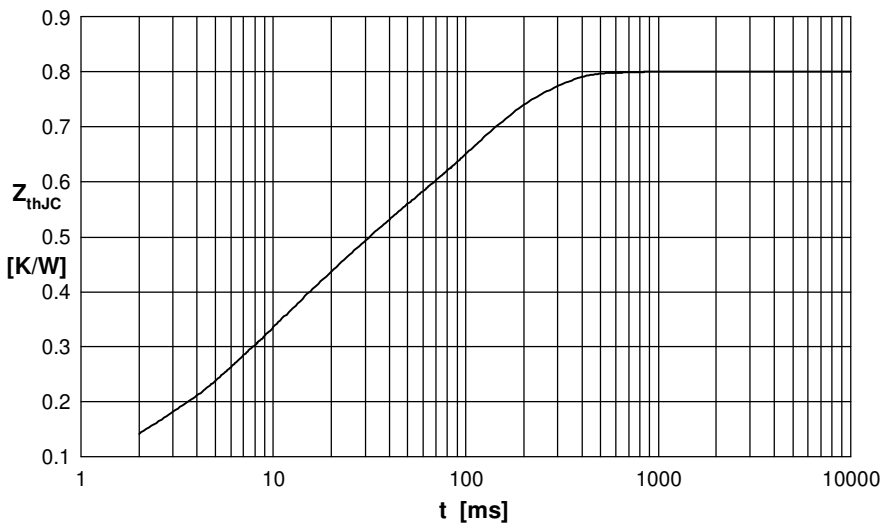


Fig. 6 Transient thermal impedance junction to case versus time per diode

Constants for Z_{thJC} calculation:

| i | R_{thi} (K/W) | t_i (s) |
|---|-----------------|-----------|
| 1 | 0.05 | 0.0006 |
| 2 | 0.13 | 0.0040 |
| 3 | 0.25 | 0.0130 |
| 4 | 0.37 | 0.1100 |